

### Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | $I_D$ |
|---------------|-----------------|-------|
| 100V          | 2.3mΩ@10V       | 300A  |

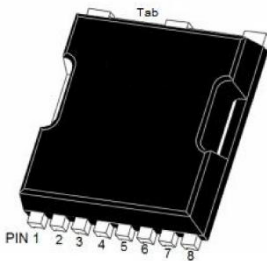
### Feature

- Excellent gate charge x  $R_{DS(on)}$  product(FOM)
- Very low on-resistance  $R_{DS(on)}$
- 175 °C operating temperature

### Application

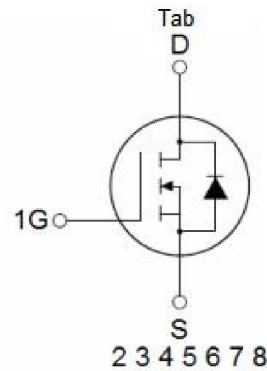
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

### Package

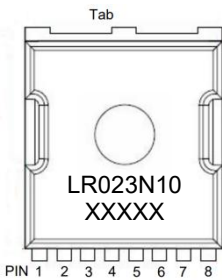


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### Circuit diagram



### Marking



### Absolute maximum ratings (Tc=25°C unless otherwise noted)

| Parameter  | Symbol           | Value      | Unit |
|--|------------------|------------|------|
| Drain-Source Voltage                             | V <sub>DS</sub>  | 100        | V    |
| Gate-Source Voltage                              | V <sub>GS</sub>  | ±20        | V    |
| Continuous Drain Current                         | I <sub>D</sub>   | 300        | A    |
| Continuous Drain Current (T <sub>C</sub> =100°C) | I <sub>D</sub>   | 220        | A    |
| Pulsed Drain Current                             | I <sub>DM</sub>  | 1200       | A    |
| Power Dissipation                                | P <sub>D</sub>   | 380        | W    |
| Thermal Resistance, Junction-to-Case             | R <sub>θJC</sub> | 0.4        | °C/W |
| Single pulse avalanche energy <sup>1)</sup>      | E <sub>AS</sub>  | 2800       | mJ   |
| Junction Temperature                             | T <sub>J</sub>   | 175        | °C   |
| Storage Temperature                              | T <sub>STG</sub> | -55 ~ +175 | °C   |

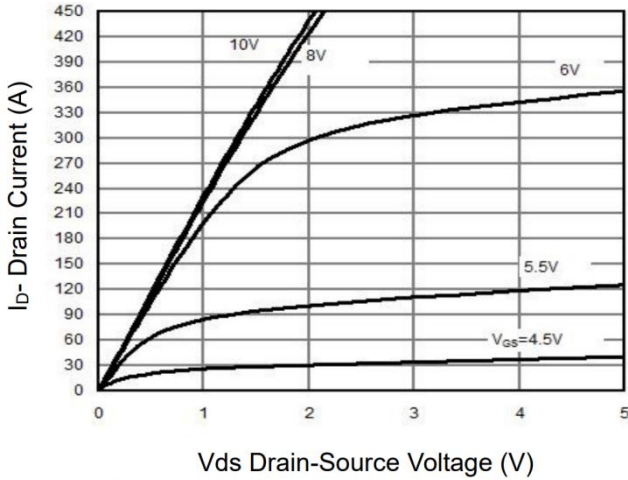
### Electrical characteristics (Tc=25°C unless otherwise noted)

| Parameter                                   | Symbol               | Test Condition  | Min. | Typ.  | Max. | Unit |
|---|----------------------|---|------|-------|------|------|
| <b>Static Characteristics</b>               |                      |   |      |       |      |      |
| Drain-source breakdown voltage              | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA   | 100  |       |      | V    |
| Zero gate voltage drain current             | I <sub>DSS</sub>     | V <sub>DS</sub> =100V, V <sub>GS</sub> = 0V   |      |       | 1    | μA   |
| Gate-body leakage current                   | I <sub>GSS</sub>     | V <sub>GS</sub> =±20V, V <sub>DS</sub> = 0V   |      |       | ±100 | nA   |
| Gate threshold voltage                      | V <sub>GS(th)</sub>  | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                  | 2.0  | 3.0   | 4.0  | V    |
| Drain-source on-resistance                  | R <sub>DS(on)</sub>  | V <sub>GS</sub> =10V, I <sub>D</sub> =150A  |      | 1.7   | 2.3  | mΩ   |
| <b>Dynamic characteristics<sup>2)</sup></b> |                      |   |      |       |      |      |
| Input Capacitance                           | C <sub>iss</sub>     | V <sub>DS</sub> =50V, V <sub>GS</sub> =0V, f =1MHz  |      | 17500 |      | pF   |
| Output Capacitance                          | C <sub>oss</sub>     |   |      | 1100  |      |      |
| Reverse Transfer Capacitance                | C <sub>rss</sub>     |   |      | 50    |      |      |
| Total Gate Charge                           | Q <sub>g</sub>       | V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =150A                          |      | 240   |      | nC   |
| Gate-Source Charge                          | Q <sub>gs</sub>      |   |      | 75    |      |      |
| Gate-Drain Charge                           | Q <sub>gd</sub>      |   |      | 60    |      |      |
| Turn-on delay time                          | t <sub>d(on)</sub>   | V <sub>DD</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =150A,<br>R <sub>G</sub> =1.6Ω |      | 34    |      | nS   |
| Turn-on rise time                           | t <sub>r</sub>       |   |      | 27    |      |      |
| Turn-off delay time                         | t <sub>d(off)</sub>  |   |      | 78    |      |      |
| Turn-off fall time                          | t <sub>f</sub>       |   |      | 30    |      |      |
| <b>Source-Drain Diode characteristics</b>   |                      |   |      |       |      |      |
| Diode Forward Current                       | I <sub>S</sub>       |   |      |       | 300  | A    |
| Diode Forward voltage                       | V <sub>SD</sub>      | V <sub>GS</sub> =0V, I <sub>S</sub> =150A   |      |       | 1.2  | V    |
| Reverse Recovery Time                       | t <sub>rr</sub>      | T <sub>J</sub> = 25°C, I <sub>F</sub> =150A   |      | 101   |      | nS   |
| Reverse Recovery Charge                     | Q <sub>rr</sub>      | di/dt = 100A/μs   |      | 280   |      | nC   |

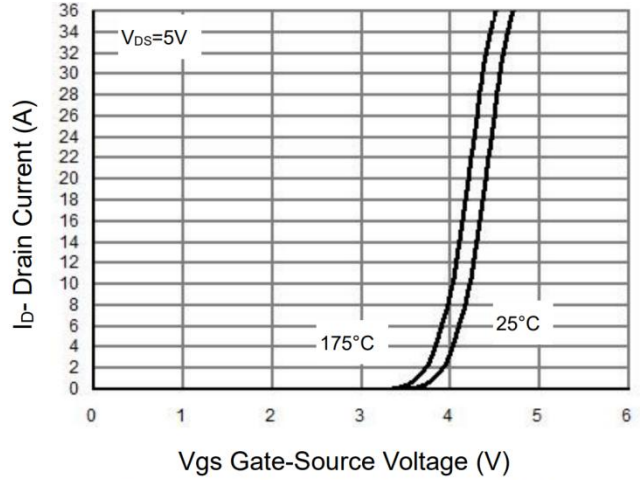
Notes:

- 1) EAS condition : T<sub>J</sub>=25°C, V<sub>DD</sub>=50V, V<sub>G</sub>=10V, L=0.5mH, R<sub>G</sub>=25Ω.
- 2) Guaranteed by design, not subject to production testing.
- 3) These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T<sub>J(MAX)</sub>=175°C. The SOA curve provides a single pulse rating.

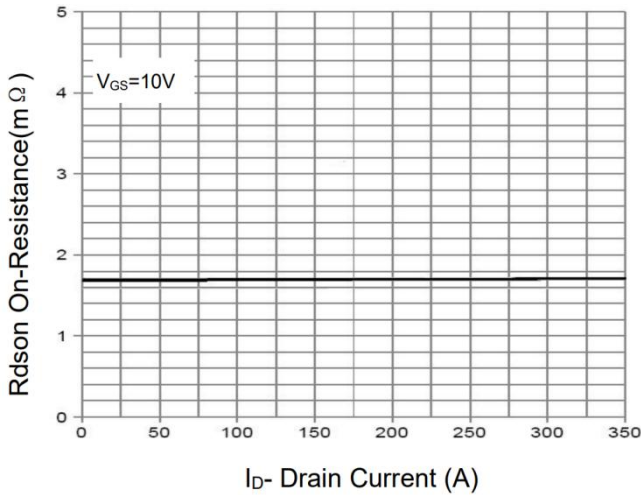
## Typical Characteristics



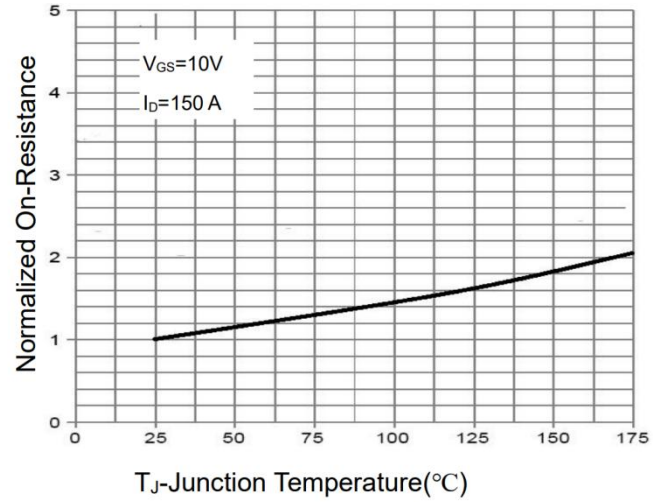
**Figure 1 Output Characteristics**



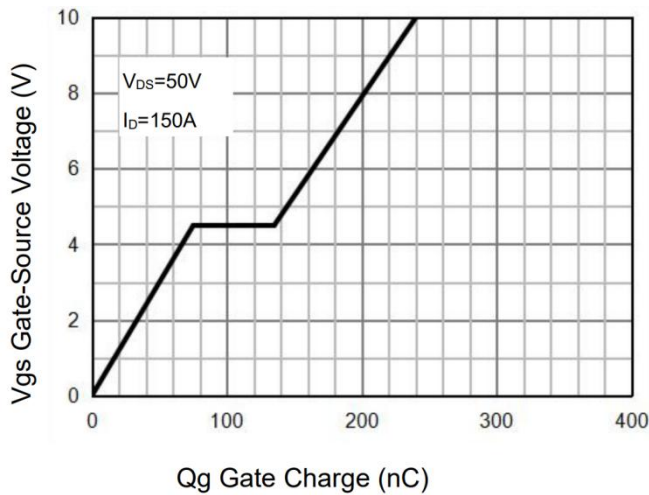
**Figure 2 Transfer Characteristics**



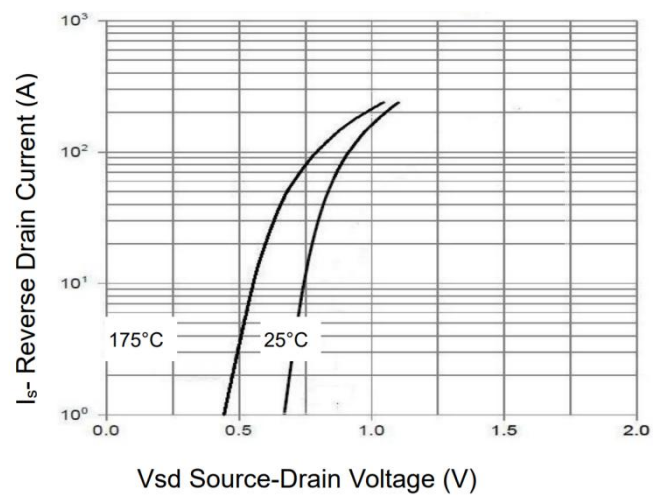
**Figure 3 Rdson- Drain Current**



**Figure 4 Rdson-Junction Temperature**

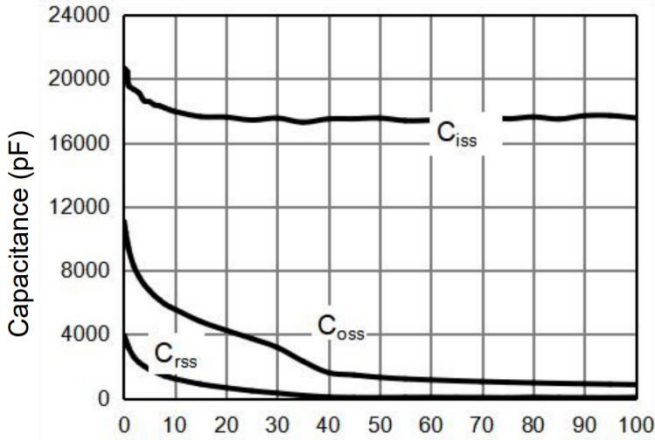


**Figure 5 Gate Charge**

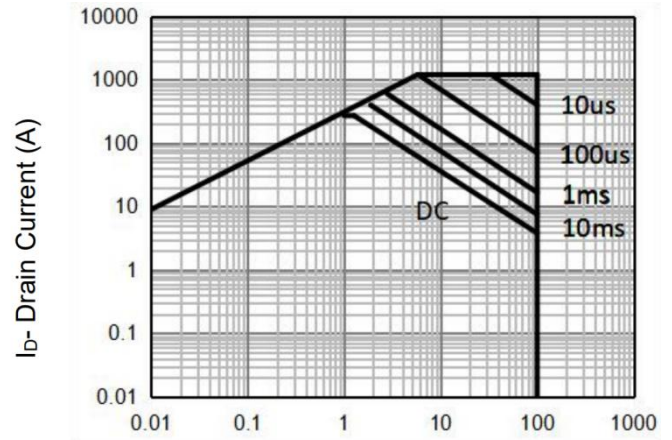


**Figure 6 Source- Drain Diode Forward**

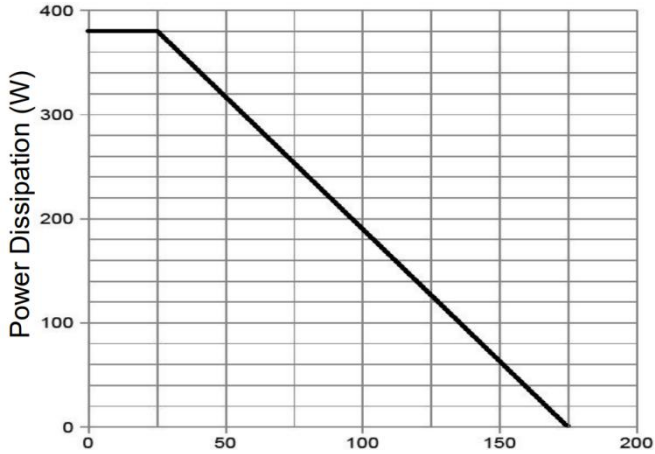
## Typical Characteristics



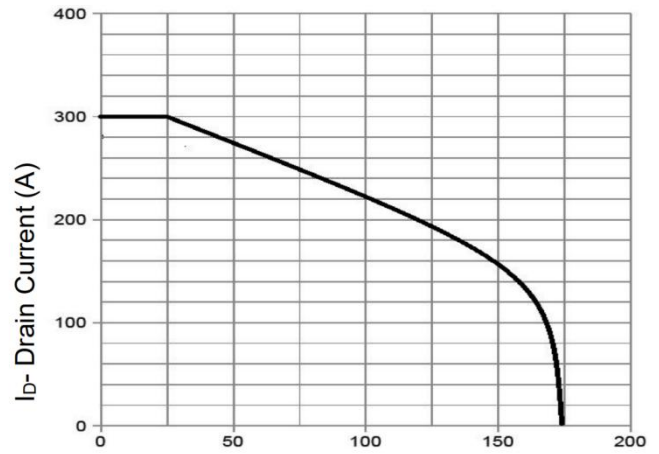
Vds Drain-Source Voltage (V)  
**Figure 7 Capacitance vs Vds**



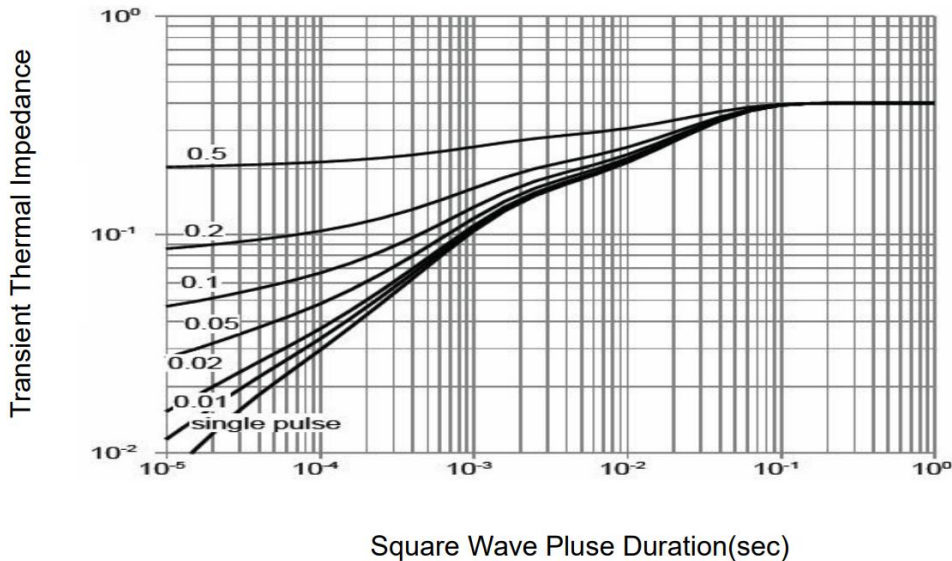
Vds Drain-Source Voltage (V)  
**Figure 8 Safe Operation Area** (Note 3)



TA-Case Temperature(°C)  
**Figure 9 Power De-rating**

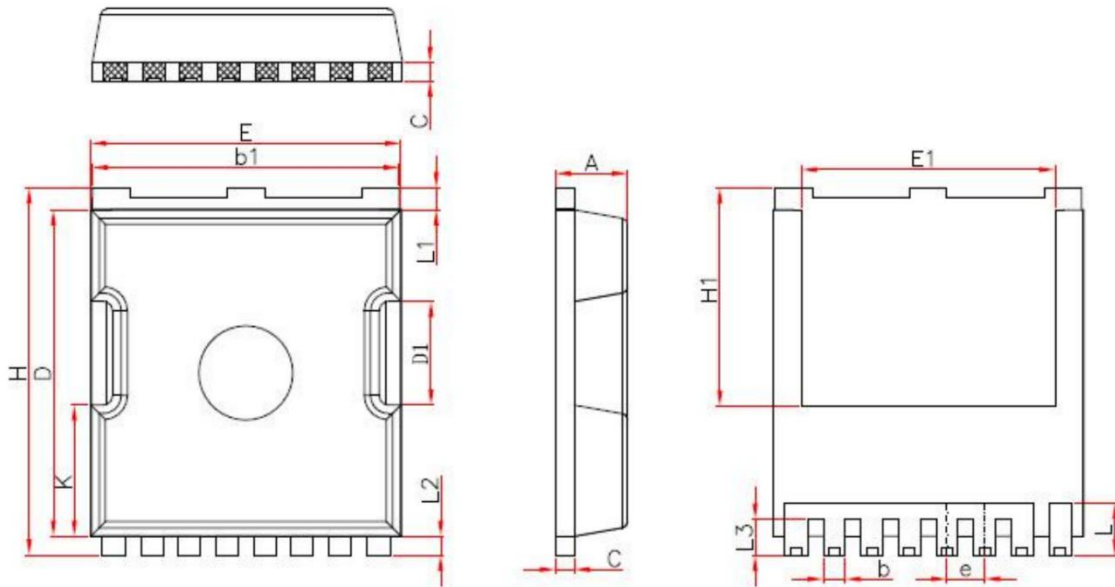


TA-Case Temperature (°C)  
**Figure 10 Current De-rating**



Square Wave Pluse Duration(sec)  
**Figure 11 Normalized Maximum Transient Thermal Impedance**

### TOLL Package Information



| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max.   | Min.                 | Max.  |
| A      | 2.200                     | 2.400  | 0.087                | 0.094 |
| b      | 0.650                     | 0.850  | 0.026                | 0.033 |
| b1     | 9.700                     | 9.900  | 0.382                | 0.390 |
| C      | 0.500                     | 0.700  | 0.020                | 0.027 |
| D      | 10.300                    | 10.500 | 0.406                | 0.413 |
| D1     | 3.150                     | 3.450  | 0.124                | 0.136 |
| E      | 9.700                     | 10.100 | 0.382                | 0.398 |
| E1     | 8.000                     | 8.200  | 0.315                | 0.323 |
| e      | 1.100                     | 1.300  | 0.043                | 0.051 |
| H      | 11.600                    | 11.800 | 0.457                | 0.465 |
| H1     | 6.850                     | 7.050  | 0.270                | 0.278 |
| K      | 4.080                     | 4.280  | 0.161                | 0.169 |
| L      | 1.600                     | 2.100  | 0.063                | 0.083 |
| L1     | 0.600                     | 0.800  | 0.024                | 0.031 |
| L2     | 0.500                     | 0.700  | 0.020                | 0.028 |
| L3     | 1.050                     | 1.300  | 0.041                | 0.051 |